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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M7
Core Size	32-Bit Single-Core
Speed	216MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, IrDA, LINbus, SAI, SD, SPDIF-Rx, SPI, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I ² S, LCD, POR, PWM, WDT
Number of I/O	82
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	320K x 8
Voltage - Supply (Vcc/Vdd)	1.7V ~ 3.6V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f746vgt6e

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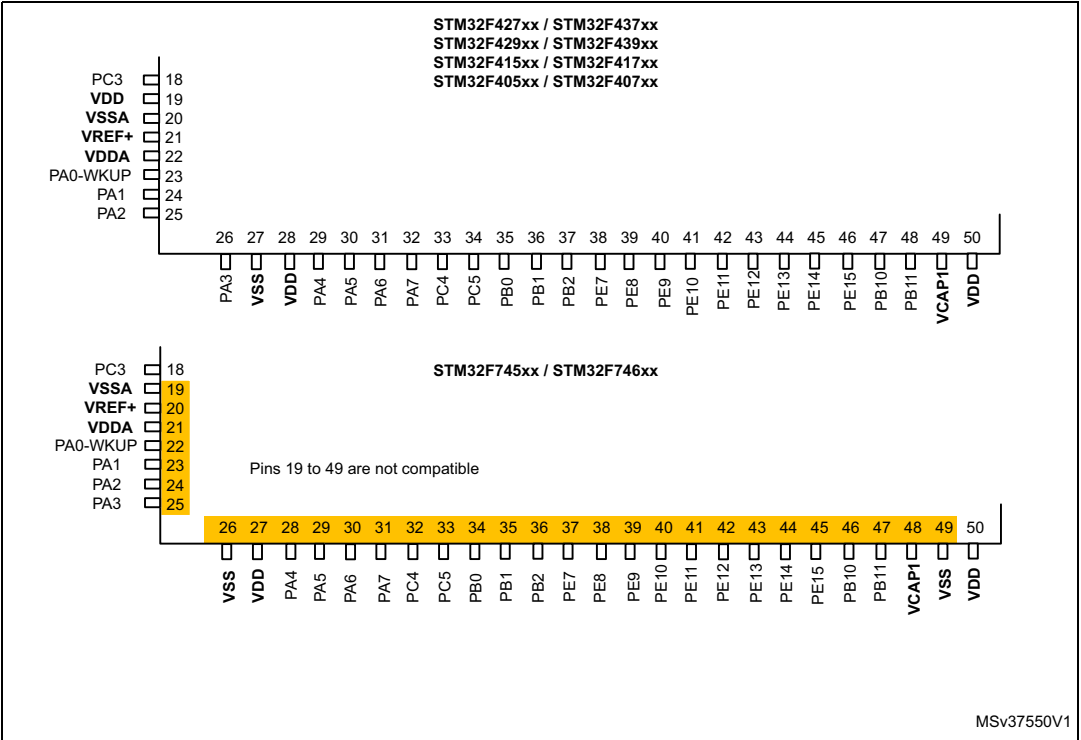
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1.1 Full compatibility throughout the family

The STM32F745xx and STM32F746xx devices are fully pin-to-pin, compatible with the STM32F4xxxx devices, allowing the user to try different peripherals, and reaching higher performances (higher frequency) for a greater degree of freedom during the development cycle.

Figure 1 give compatible board designs between the STM32F4xx families.

Figure 1. Compatible board design for LQFP100 package



The STM32F745xx and STM32F746xx LQFP144, LQFP176, LQFP208, TFBGA216, UFBGA176, WLCSP143 packages are fully pin to pin compatible with STM32F4xxxx devices.

2.15 Boot modes

At startup, the boot memory space is selected by the BOOT pin and BOOT_ADDx option bytes, allowing to program any boot memory address from 0x0000 0000 to 0x3FFF FFFF which includes:

- All Flash address space mapped on ITCM or AXIM interface
- All RAM address space: ITCM, DTCM RAMs and SRAMs mapped on AXIM interface
- The System memory bootloader

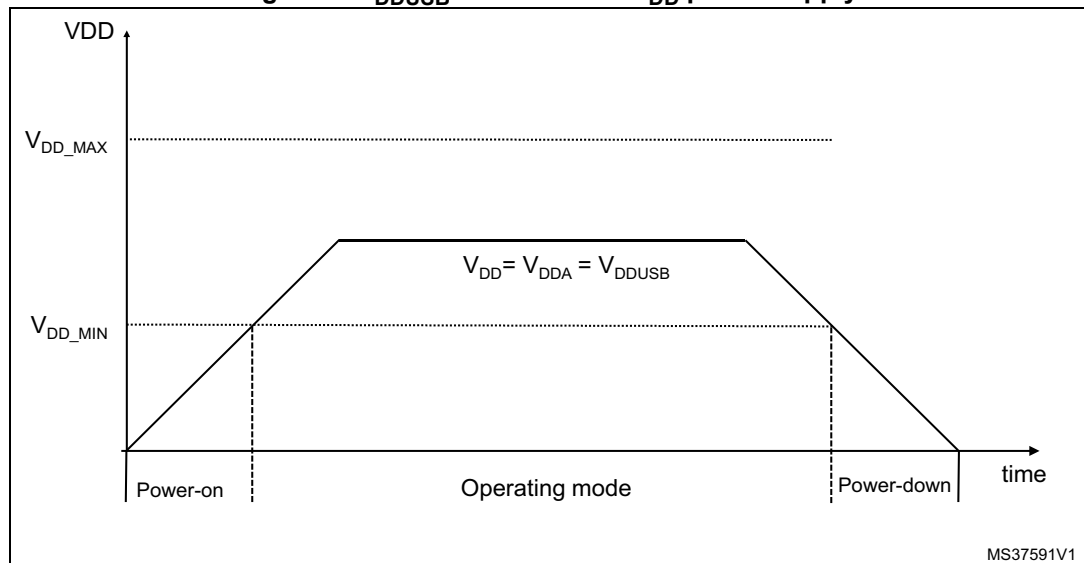
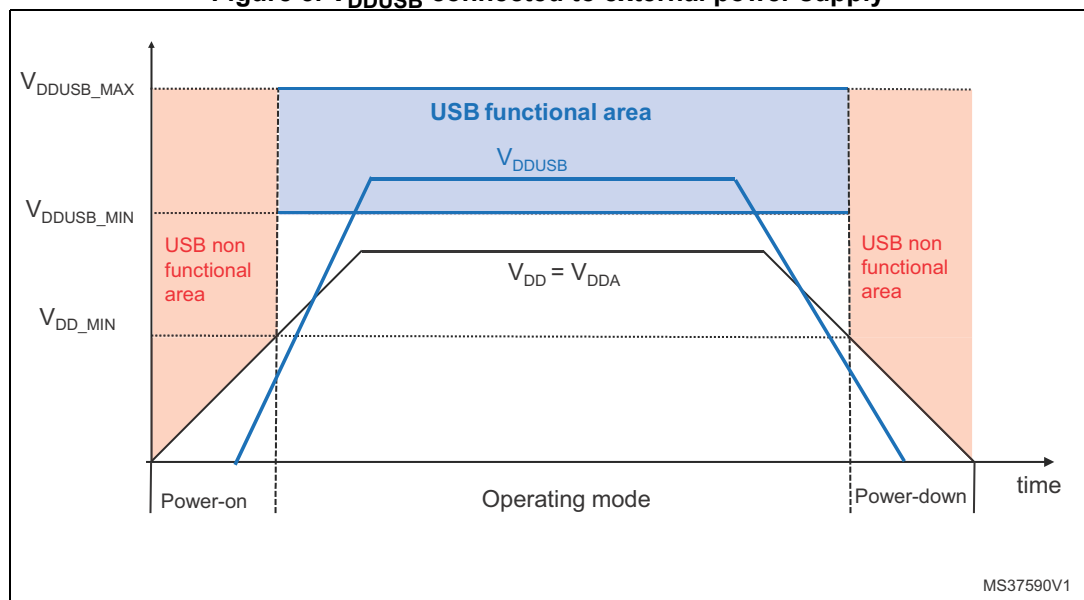
The boot loader is located in system memory. It is used to reprogram the Flash memory through a serial interface.

2.16 Power supply schemes

- V_{BAT} = 1.65 to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when V_{DD} is not present.
- V_{DD} = 1.7 to 3.6 V external power supply for I/Os and the internal regulator (when enabled), provided externally through V_{DD} pins.
- V_{SSA} , V_{DDA} = 1.7 to 3.6 V: external analog power supplies for ADC, DAC, reset blocks, RCs and PLL. V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS} , respectively.

Note: V_{DD}/V_{DDA} minimum value of 1.7 V is obtained when the internal reset is OFF (refer to [Section 2.17.2: Internal reset OFF](#)). Refer to [Table 3: Voltage regulator configuration mode versus device operating mode](#) to identify the packages supporting this option.

- V_{DDUSB} can be connected either to V_{DD} or an external independent power supply (3.0 to 3.6V) for USB transceivers (refer to [Figure 4](#) and [Figure 5](#)). For example, when device is powered at 1.8V, an independent power supply 3.3V can be connected to V_{DDUSB} . When the V_{DDUSB} is connected to a separated power supply, it is independent from V_{DD} or V_{DDA} but it must be the last supply to be provided and the first to disappear. The following conditions V_{DDUSB} must be respected:
 - During power-on phase ($V_{DD} < V_{DD_MIN}$), V_{DDUSB} should be always lower than V_{DD}
 - During power-down phase ($V_{DD} < V_{DD_MIN}$), V_{DDUSB} should be always lower than V_{DD}
 - V_{DDUSB} rising and falling time rate specifications must be respected (see [Table 20](#) and [Table 21](#))
 - In operating mode phase, V_{DDUSB} could be lower or higher than V_{DD} :
 - If USB (USB OTG_HS/OTG_FS) is used, the associated GPIOs powered by V_{DDUSB} are operating between V_{DDUSB_MIN} and V_{DDUSB_MAX} .
 - The V_{DDUSB} supply both USB transceiver (USB OTG_HS and USB OTG_FS). If only one USB transceiver is used in the application, the GPIOs associated to the other USB transceiver are still supplied by V_{DDUSB} .
 - If USB (USB OTG_HS/OTG_FS) is not used, the associated GPIOs powered by V_{DDUSB} are operating between V_{DD_MIN} and V_{DD_MAX} .

Figure 4. V_{DDUSB} connected to V_{DD} power supplyFigure 5. V_{DDUSB} connected to external power supply

2.17 Power supply supervisor

2.17.1 Internal reset ON

On packages embedding the PDR_ON pin, the power supply supervisor is enabled by holding PDR_ON high. On the other packages, the power supply supervisor is always enabled.

The device has an integrated power-on reset (POR)/ power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry. At power-on, POR/PDR is always active and ensures proper operation starting from 1.8 V. After the 1.8 V POR threshold level is

2.32 Controller area network (bxCAN)

The two CANs are compliant with the 2.0A and B (active) specifications with a bitrate up to 1 Mbit/s. They can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. Each CAN has three transmit mailboxes, two receive FIFOs with 3 stages and 28 shared scalable filter banks (all of them can be used even if one CAN is used). 256 bytes of SRAM are allocated for each CAN.

2.33 Universal serial bus on-the-go full-speed (OTG_FS)

The device embeds an USB OTG full-speed device/host/OTG peripheral with integrated transceivers. The USB OTG FS peripheral is compliant with the USB 2.0 specification and with the OTG 2.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator.

The major features are:

- Combined Rx and Tx FIFO size of 1.28 Kbytes with dynamic FIFO sizing
- Support of the session request protocol (SRP) and host negotiation protocol (HNP)
- 1 bidirectional control endpoint + 5 IN endpoints + 5 OUT endpoints
- 12 host channels with periodic OUT support
- Software configurable to OTG1.3 and OTG2.0 modes of operation
- USB 2.0 LPM (Link Power Management) support
- Internal FS OTG PHY support
- HNP/SNP/IP inside (no need for any external resistor)

For OTG/Host modes, a power switch is needed in case bus-powered devices are connected

2.34 Universal serial bus on-the-go high-speed (OTG_HS)

The device embeds a USB OTG high-speed (up to 480 Mb/s) device/host/OTG peripheral. The USB OTG HS supports both full-speed and high-speed operations. It integrates the transceivers for full-speed operation (12 MB/s) and features a UTMI low-pin interface (ULPI) for high-speed operation (480 MB/s). When using the USB OTG HS in HS mode, an external PHY device connected to the ULPI is required.

The USB OTG HS peripheral is compliant with the USB 2.0 specification and with the OTG 2.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator.

2.38 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

The I/O configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

Fast I/O handling allowing maximum I/O toggling up to 108 MHz.

2.39 Analog-to-digital converters (ADCs)

Three 12-bit analog-to-digital converters are embedded and each ADC shares up to 16 external channels, performing conversions in the single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold

The ADC can be served by the DMA controller. An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

To synchronize A/D conversion and timers, the ADCs could be triggered by any of TIM1, TIM2, TIM3, TIM4, TIM5, or TIM8 timer.

2.40 Temperature sensor

The temperature sensor has to generate a voltage that varies linearly with temperature. The conversion range is between 1.7 V and 3.6 V. The temperature sensor is internally connected to the same input channel as V_{BAT} , ADC1_IN18, which is used to convert the sensor output voltage into a digital value. When the temperature sensor and V_{BAT} conversion are enabled at the same time, only V_{BAT} conversion is performed.

As the offset of the temperature sensor varies from chip to chip due to process variation, the internal temperature sensor is mainly suitable for applications that detect temperature changes instead of absolute temperatures. If an accurate temperature reading is needed, then an external temperature sensor part should be used.

2.41 Digital-to-analog converter (DAC)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs.

Table 10. STM32F745xx and STM32F746xx pin and ball definition (continued)

Pin Number								Pin name (function after reset) ⁽¹⁾	Pin type	I/O structure	Notes	Alternate functions	Additional functions
LQFP100	TFBGA100	WLCSP143	LQFP144	UFBGA176	LQFP176	LQFP208	TFBGA216						
-	-	G2	93	H14	112	135	H14	PG8	I/O	FT	-	SPI6_NSS, SPDIFRX_IN2, USART6_RTS, ETH_PPS_OUT, FMC_SDCLK, EVENTOUT	-
-	-	D2	94	G12	113	136	G10	VSS	S	-	-	-	-
-	F6	G1	95	H13	114	137	G11	VDDUSB	S	-	-	-	-
63	F10	F2	96	H15	115	138	H15	PC6	I/O	FT	-	TIM3_CH1, TIM8_CH1, I2S2_MCK, USART6_TX, SDMMC1_D6, DCMI_D0, LCD_HSYNC, EVENTOUT	-
64	E10	F3	97	G15	116	139	G15	PC7	I/O	FT	-	TIM3_CH2, TIM8_CH2, I2S3_MCK, USART6_RX, SDMMC1_D7, DCMI_D1, LCD_G6, EVENTOUT	-
65	F9	E4	98	G14	117	140	G14	PC8	I/O	FT	-	TRACED1, TIM3_CH3, TIM8_CH3, UART5_RTS, USART6_CK, SDMMC1_D0, DCMI_D2, EVENTOUT	-
66	E9	E3	99	F14	118	141	F14	PC9	I/O	FT	-	MCO2, TIM3_CH4, TIM8_CH4, I2C3_SDA, I2S_CKIN, UART5_CTS, QUADSPI_BK1_IO0, SDMMC1_D1, DCMI_D3, EVENTOUT	-
67	D9	F1	100	F15	119	142	F15	PA8	I/O	FT	-	MCO1, TIM1_CH1, TIM8_BKIN2, I2C3_SCL, USART1_CK, OTG_FS_SOF, LCD_R6, EVENTOUT	-
68	C9	E2	101	E15	120	143	E15	PA9	I/O	FT	-	TIM1_CH2, I2C3_SMBA, SPI2_SCK/I2S2_CK, USART1_TX, DCMI_D0, EVENTOUT	OTG_FS_VB US

Table 10. STM32F745xx and STM32F746xx pin and ball definition (continued)

Pin Number								Pin name (function after reset) ⁽¹⁾	Pin type	I/O structure	Notes	Alternate functions	Additional functions
LQFP100	TFBGA100	WLCSP143	LQFP144	UFBGA176	LQFP176	LQFP208	TFBGA216						
-	-	-	-	-	-	186	D8	PK3	I/O	FT	-	LCD_B4, EVENTOUT	-
-	-	-	-	-	-	187	D7	PK4	I/O	FT	-	LCD_B5, EVENTOUT	-
-	-	-	-	-	-	188	C6	PK5	I/O	FT	-	LCD_B6, EVENTOUT	-
-	-	-	-	-	-	189	C5	PK6	I/O	FT	-	LCD_B7, EVENTOUT	-
-	-	-	-	-	-	190	C4	PK7	I/O	FT	-	LCD_DE, EVENTOUT	-
-	-	A7	132	B7	160	191	B7	PG15	I/O	FT	-	USART6_CTS, FMC_SDNCAS, DCMI_D13, EVENTOUT	-
89	A7	B7	133	A10	161	192	A10	PB3(JTD O/TRAC ESWO)	I/O	FT	-	JTDO/TRACESWO, TIM2_CH2, SPI1_SCK/I2S1_CK, SPI3_SCK/I2S3_CK, EVENTOUT	-
90	A6	C7	134	A9	162	193	A9	PB4(NJT RST)	I/O	FT	-	NJTRST, TIM3_CH1, SPI1_MISO, SPI3_MISO, SPI2_NSS/I2S2_WS, EVENTOUT	-
91	C5	C8	135	A6	163	194	A8	PB5	I/O	FT	-	TIM3_CH2, I2C1_SMBA, SPI1_MOSI/I2S1_SD, SPI3_MOSI/I2S3_SD, CAN2_RX, OTG_HS_ULPI_D7, ETH_PPS_OUT, FMC_SDCKE1, DCMI_D10, EVENTOUT	-
92	B5	A8	136	B6	164	195	B6	PB6	I/O	FT	-	TIM4_CH1, HDMI-CEC, I2C1_SCL, USART1_TX, CAN2_TX, QUADSPI_BK1_NCS, FMC_SDNE1, DCMI_D5, EVENTOUT	-
93	A5	B8	137	B5	165	196	B5	PB7	I/O	FT	-	TIM4_CH2, I2C1_SDA, USART1_RX, FMC_NL, DCMI_VSYNC, EVENTOUT	-
94	D5	C9	138	D6	166	197	E6	BOOT	I	B	-	-	VPP



Table 12. STM32F745xx and STM32F746xx alternate function mapping (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS	TIM1/2	TIM3/4/5	TIM8/9/10/ 11/LPTIM 1/CEC	I2C1/2/3/ 4/CEC	SPI1/2/3/ 4/5/6	SPI3/ SAI1	SPI2/3/U SART1/2/ 3/UART5/ SPDIFRX	SAI2/US ART6/UA RT4/5/7/8 /SPDIFR X	CAN1/2/T IM12/13/ 14/QUAD SPI/LCD	SAI2/QU ADSPI/O TG2_HS/ OTG1_FS	ETH/ OTG1_FS	FMC/SD MMC1/O TG2_FS	DCMI	LCD	SYS
Port B	PB9	-	-	TIM4_C H4	TIM11_CH 1	I2C1_SD A	SPI2_NS S/I2S2_ WS	-	-	-	CAN1_T X	-	-	SDMMC 1_D5	DCMI_D 7	LCD_B7	EVEN TOUT
	PB10	-	TIM2_C H3	-	-	I2C2_SC L	SPI2_SC K/I2S2_ CK	-	USART3 _TX	-	-	OTG_HS_ ULPI_D3	ETH_MII_ RX_ER	-	-	LCD_G4	EVEN TOUT
	PB11	-	TIM2_C H4	-	-	I2C2_SD A	-	-	USART3 _RX	-	-	OTG_HS_ ULPI_D4	ETH_MII_ TX_EN/ ETH_RMII_ TX_EN	-	-	LCD_G5	EVEN TOUT
	PB12	-	TIM1_B KIN	-	-	I2C2_SM BA	SPI2_NS S/I2S2_ WS	-	USART3 _CK	-	CAN2_R X	OTG_HS_ ULPI_D5	ETH_MII_ TXD0/ET H_RMII_T XD0	OTG_HS _ID	-	-	EVEN TOUT
	PB13	-	TIM1_C H1N	-	-	-	SPI2_SC K/I2S2_ CK	-	USART3 _CTS	-	CAN2_T X	OTG_HS_ ULPI_D6	ETH_MII_ TXD1/ET H_RMII_T XD1	-	-	-	EVEN TOUT
	PB14	-	TIM1_C H2N	-	TIM8_CH 2N	-	SPI2_MI SO	-	USART3 _RTS	-	TIM12_C H1	-	-	OTG_HS _DM	-	-	EVEN TOUT
	PB15	RTC_R EFIN	TIM1_C H3N	-	TIM8_CH 3N	-	SPI2_M OSI/I2S2 _SD	-	-	-	TIM12_C H2	-	-	OTG_HS _DP	-	-	EVEN TOUT
Port C	PC0	-	-	-	-	-	-	-	-	SAI2_FS _B	-	OTG_HS_ ULPI_ST P	-	FMC_SD NWE	-	LCD_R5	EVEN TOUT
	PC1	TRACE D0	-	-	-	-	SPI2_M OSI/I2S2 _SD	SAI1_SD _A	-	-	-	-	ETH_MD C	-	-	-	EVEN TOUT
	PC2	-	-	-	-	-	SPI2_MI SO	-	-	-	-	OTG_HS_ ULPI_DIR	ETH_MII_ TXD2	FMC_SD NE0	-	-	EVEN TOUT
	PC3	-	-	-	-	-	SPI2_M OSI/I2S2 _SD	-	-	-	-	OTG_HS_ ULPI_NX T	ETH_MII_ TX_CLK	FMC_SD CKE0	-	-	EVEN TOUT

Table 12. STM32F745xx and STM32F746xx alternate function mapping (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS	TIM1/2	TIM3/4/5	TIM8/9/10/11/LPTIM1/CEC	I2C1/2/3/4/CEC	SPI1/2/3/4/5/6	SPI3/SAI1	SPI2/3/UART1/2/3/UART5/SPDIFRX	SAI2/USART6/UART4/5/7/8/SPDIFRX	CAN1/2/TIM12/13/14/QUADSPI/LCD	SAI2/QUADSPI/TG2_HS/OTG1_FS	ETH/OTG1_FS	FMC/SDMMC1/O TG2_FS	DCMI	LCD	SYS
Port D	PD14	-	-	TIM4_C H3	-	-	-	-	-	UART8_CTS	-	-	-	FMC_D0	-	-	EVEN TOUT
	PD15	-	-	TIM4_C H4	-	-	-	-	-	UART8_RTS	-	-	-	FMC_D1	-	-	EVEN TOUT
Port E	PE0	-	-	TIM4_ET R	LPTIM1_ETR	-	-	-	-	UART8_Rx	-	SAI2_MC K_A	-	FMC_NB L0	DCMI_D 2	-	EVEN TOUT
	PE1	-	-	-	LPTIM1_I N2	-	-	-	-	UART8_T x	-	-	-	FMC_NB L1	DCMI_D 3	-	EVEN TOUT
	PE2	TRACE CLK	-	-	-	-	SPI4_SC K	SAI1_M CLK_A	-	-	QUADSP I_BK1_IO 2	-	ETH_MII_TXD3	FMC_A2 3	-	-	EVEN TOUT
	PE3	TRACE D0	-	-	-	-	-	SAI1_SD _B	-	-	-	-	-	FMC_A1 9	-	-	EVEN TOUT
	PE4	TRACE D1	-	-	-	-	SPI4_NS S	SAI1_FS _A	-	-	-	-	-	FMC_A2 0	DCMI_D 4	LCD_B0	EVEN TOUT
	PE5	TRACE D2	-	-	TIM9_CH 1	-	SPI4_MI SO	SAI1_SC K_A	-	-	-	-	-	FMC_A2 1	DCMI_D 6	LCD_G0	EVEN TOUT
	PE6	TRACE D3	TIM1_B KIN2	-	TIM9_CH 2	-	SPI4_M OSI	SAI1_SD _A	-	-	-	SAI2_MC K_B	-	FMC_A2 2	DCMI_D 7	LCD_G1	EVEN TOUT
	PE7	-	TIM1_ET R	-	-	-	-	-	-	UART7_Rx	-	QUADSPI _BK2_IO0	-	FMC_D4	-	-	EVEN TOUT
	PE8	-	TIM1_C H1N	-	-	-	-	-	-	UART7_T x	-	QUADSPI _BK2_IO1	-	FMC_D5	-	-	EVEN TOUT
	PE9	-	TIM1_C H1	-	-	-	-	-	-	UART7_RTS	-	QUADSPI _BK2_IO2	-	FMC_D6	-	-	EVEN TOUT
	PE10	-	TIM1_C H2N	-	-	-	-	-	-	UART7_CTS	-	QUADSPI _BK2_IO3	-	FMC_D7	-	-	EVEN TOUT
	PE11	-	TIM1_C H2	-	-	-	SPI4_NS S	-	-	-	-	SAI2_SD _B	-	FMC_D8	-	LCD_G3	EVEN TOUT
	PE12	-	TIM1_C H3N	-	-	-	SPI4_SC K	-	-	-	-	SAI2_SC K_B	-	FMC_D9	-	LCD_B4	EVEN TOUT
	PE13	-	TIM1_C H3	-	-	-	SPI4_MI SO	-	-	-	-	SAI2_FS _B	-	FMC_D1 0	-	LCD_DE	EVEN TOUT

Table 17. General operating conditions (continued)

Symbol	Parameter	Conditions ⁽¹⁾	Min	Typ	Max	Unit
V_{12}	Regulator ON: 1.2 V internal voltage on V_{CAP_1}/V_{CAP_2} pins	Power Scale 3 ((VOS[1:0] bits in PWR_CR register = 0x01), 144 MHz HCLK max frequency	1.08	1.14	1.20	V
		Power Scale 2 ((VOS[1:0] bits in PWR_CR register = 0x10), 168 MHz HCLK max frequency with over-drive OFF or 180 MHz with over-drive ON	1.20	1.26	1.32	
		Power Scale 1 ((VOS[1:0] bits in PWR_CR register = 0x11), 180 MHz HCLK max frequency with over-drive OFF or 216 MHz with over-drive ON	1.26	1.32	1.40	
	Regulator OFF: 1.2 V external voltage must be supplied from external regulator on V_{CAP_1}/V_{CAP_2} pins ⁽⁷⁾	Max frequency 144 MHz	1.10	1.14	1.20	
		Max frequency 168MHz	1.20	1.26	1.32	
		Max frequency 180 MHz	1.26	1.32	1.38	
V_{IN}	Input voltage on RST and FT pins ⁽⁸⁾	$2\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	- 0.3	-	5.5	
		$V_{DD} \leq 2\text{ V}$	- 0.3	-	5.2	
	Input voltage on TTa pins	-	- 0.3	-	$V_{DDA} + 0.3$	
	Input voltage on BOOT pin	-	0	-	9	
P_D	Power dissipation at $T_A = 85\text{ °C}$ for suffix 6 or $T_A = 105\text{ °C}$ for suffix 7 ⁽⁹⁾	LQFP100	-	-	465	mW
		TFBGA100	-	-	351	
		WLCSP143	-	-	641	
		LQFP144	-	-	500	
		LQFP176	-	-	526	
		UFBGA176	-	-	513	
		LQFP208	-	-	1053	
		TFBGA216	-	-	690	
T_A	Ambient temperature for 6 suffix version	Maximum power dissipation	- 40	-	85	°C
		Low power dissipation ⁽¹⁰⁾	- 40	-	105	
	Ambient temperature for 7 suffix version	Maximum power dissipation	- 40	-	105	°C
		Low power dissipation ⁽¹⁰⁾	- 40	-	125	
T_J	Junction temperature range	6 suffix version	- 40	-	105	°C
		7 suffix version	- 40	-	125	

1. The over-drive mode is not supported at the voltage ranges from 1.7 to 2.1 V.
2. 216 MHz maximum frequency for 6 suffix version (200 MHz maximum frequency for 7 suffix version).
3. V_{DD}/V_{DDA} minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to [Section 2.17.2: Internal reset OFF](#)).
4. When the ADC is used, refer to [Table 62: ADC characteristics](#).
5. If V_{REF+} pin is present, it must respect the following condition: $V_{DDA} - V_{REF+} < 1.2\text{ V}$.

Table 29. Typical and maximum current consumption in Sleep mode, regulator ON

Symbol	Parameter	Conditions	f _{HCLK} (MHz)	Typ	Max ⁽¹⁾			Unit
					T _A = 25 °C	T _A = 85 °C	T _A = 105 °C	
I _{DD}	Supply current in Sleep mode	All peripherals enabled ⁽²⁾	216	116	137 ⁽³⁾	159 ⁽³⁾	-	mA
			200	108	127	147	166	
			180	95	112 ⁽³⁾	126 ⁽³⁾	140 ⁽³⁾	
			168	85	99	112	125	
			144	65	76	87	98	
			60	30	35	46	57	
			25	15	18	29	39	
		All peripherals disabled	216	35	46 ⁽³⁾	71 ⁽³⁾	-	
			200	32	43	66	86	
			180	28	38 ⁽³⁾	53 ⁽³⁾	70 ⁽³⁾	
			168	25	33	47	61	
			144	20	26	37	50	
			60	10	14	26	36	
			25	5	8	20	31	

1. Guaranteed by characterization results.

2. When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.

3. Guaranteed by test in production.

Table 30. Typical and maximum current consumption in Sleep mode, regulator OFF

Symbol	Parameter	Conditions	f _{HCLK} (MHz)	Typ		Max ⁽¹⁾						Unit
						TA= 25 °C		TA= 85 °C		TA= 105 °C		
				IDD12	IDD	IDD12	IDD	IDD12	IDD	IDD12	IDD	
IDD12/ IDD	Supply current in RUN mode from V12 and V _{DD} supply	All Peripherals Enabled ⁽²⁾	180	94	1	110	2	125	2	138	2	mA
			168	83	1	96	2	111	2	123	2	
			144	64	1	74	2	85	2	96	2	
			60	29	1	34	2	44	2	55	2	
			25	14	1	16	2	27	2	37	2	
		All Peripherals Disabled	180	27	1	36	2	51	2	68	2	
			168	24	1	31	2	45	2	59	2	
			144	18	1	24	2	35	2	48	2	
			60	9	1	12	2	24	2	34	2	
			25	4	1	6	2	18	2	29	2	

1. Guaranteed by characterization results.

Table 34. Switching output I/O current consumption⁽¹⁾ (continued)

Symbol	Parameter	Conditions	I/O toggling frequency (fsw) MHz	Typ V _{DD} = 3.3 V	Typ V _{DD} = 1.8 V	Unit
I _{DDIO}	I/O switching Current	C _{EXT} = 22 pF C = C _{INT} + C _S + C _{EXT}	2	0.3	0.1	mA
			8	1.0	0.5	
			25	3.5	1.6	
			50	5.9	4.2	
			60	10.0	4.4	
			84	19.12	5.8	
			90	19.6	-	
		C _{EXT} = 33 pF C = C _{INT} + C _S + C _{EXT}	2	0.3	0.2	
			8	1.3	0.7	
			25	3.5	2.3	
			50	10.26	5.19	
			60	16.53	-	

1. C_{INT} + C_S, PCB board capacitance including the pad pin is estimated to 15 pF.

On-chip peripheral current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are in analog input configuration.
- All peripherals are disabled unless otherwise mentioned.
- I/O compensation cell enabled.
- The ART/L1-cache is ON.
- Scale 1 mode selected, internal digital voltage V_{I2} = 1.32 V.
- HCLK is the system clock. f_{PCLK1} = f_{HCLK}/4, and f_{PCLK2} = f_{HCLK}/2.

The given value is calculated by measuring the difference of current consumption

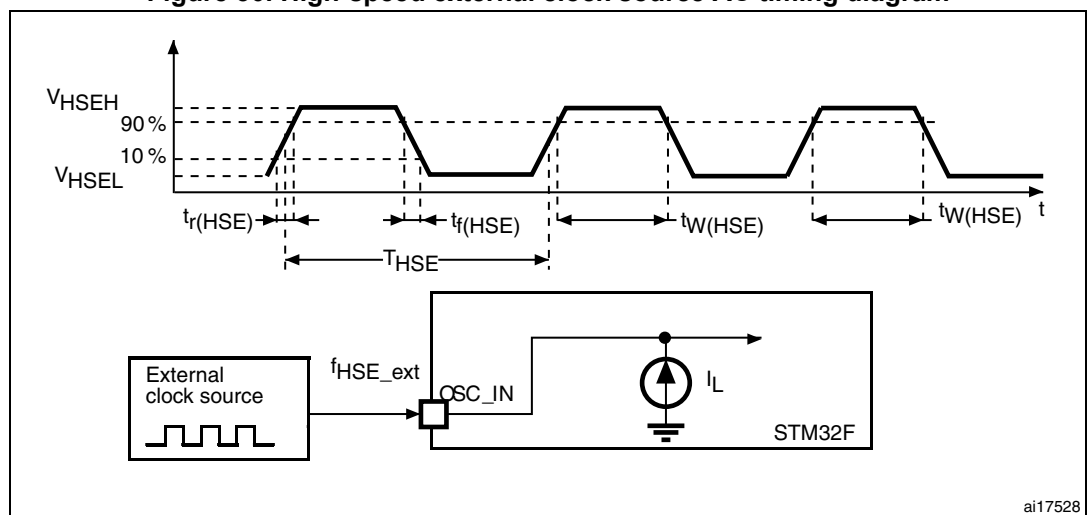
- with all peripherals clocked off
- with only one peripheral clocked on
- f_{HCLK} = 216 MHz (Scale 1 + over-drive ON), f_{HCLK} = 168 MHz (Scale 2), f_{HCLK} = 144 MHz (Scale 3)
- Ambient operating temperature is 25 °C and V_{DD}=3.3 V.

Table 38. Low-speed external user clock characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{LSE_ext}	User External clock source frequency ⁽¹⁾	-	-	32.768	1000	kHz
V_{LSEH}	OSC32_IN input pin high level voltage		$0.7V_{DD}$	-	V_{DD}	V
V_{LSEL}	OSC32_IN input pin low level voltage		V_{SS}	-	$0.3V_{DD}$	
$t_{w(LSE)}$ $t_{f(LSE)}$	OSC32_IN high or low time ⁽¹⁾		450	-	-	ns
$t_{r(LSE)}$ $t_{f(LSE)}$	OSC32_IN rise or fall time ⁽¹⁾		-	-	50	
$C_{in(LSE)}$	OSC32_IN input capacitance ⁽¹⁾	-	-	5	-	pF
$DuCy_{(LSE)}$	Duty cycle	-	30	-	70	%
I_L	OSC32_IN Input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	± 1	μA

1. Guaranteed by design.

Figure 30. High-speed external clock source AC timing diagram



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Table 45. PLLISAI characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Jitter ⁽³⁾	Master SAI clock jitter	Cycle to cycle at 12.288 MHz on 48KHz period, N=432, R=5	RMS	-	90	-
			peak to peak	-	±280	ps
		Average frequency of 12.288 MHz N = 432, R = 5 on 1000 samples	-	90	-	ps
	FS clock jitter	Cycle to cycle at 48 KHz on 1000 samples	-	400	-	ps
I _{DD(PLLISAI)} ⁽⁴⁾	PLLISAI power consumption on V _{DD}	VCO freq = 100 MHz VCO freq = 432 MHz	0.15 0.45	-	0.40 0.75	mA
I _{DDA(PLLISAI)} ⁽⁴⁾	PLLISAI power consumption on V _{DDA}	VCO freq = 100 MHz VCO freq = 432 MHz	0.30 0.55	-	0.40 0.85	mA

1. Take care of using the appropriate division factor M to have the specified PLL input clock values.
2. Guaranteed by design.
3. Value given with main PLL running.
4. Guaranteed by characterization results.

5.3.12 PLL spread spectrum clock generation (SSCG) characteristics

The spread spectrum clock generation (SSCG) feature allows to reduce electromagnetic interferences (see [Table 52: EMI characteristics](#)). It is available only on the main PLL.

Table 46. SSCG parameters constraint

Symbol	Parameter	Min	Typ	Max ⁽¹⁾	Unit
f _{Mod}	Modulation frequency	-	-	10	KHz
md	Peak modulation depth	0.25	-	2	%
MODEPER * INCSTEP	-	-	-	2 ¹⁵ - 1	-

1. Guaranteed by design.

Equation 1

The frequency modulation period (MODEPER) is given by the equation below:

$$\text{MODEPER} = \text{round}[f_{\text{PLL_IN}} / (4 \times f_{\text{Mod}})]$$

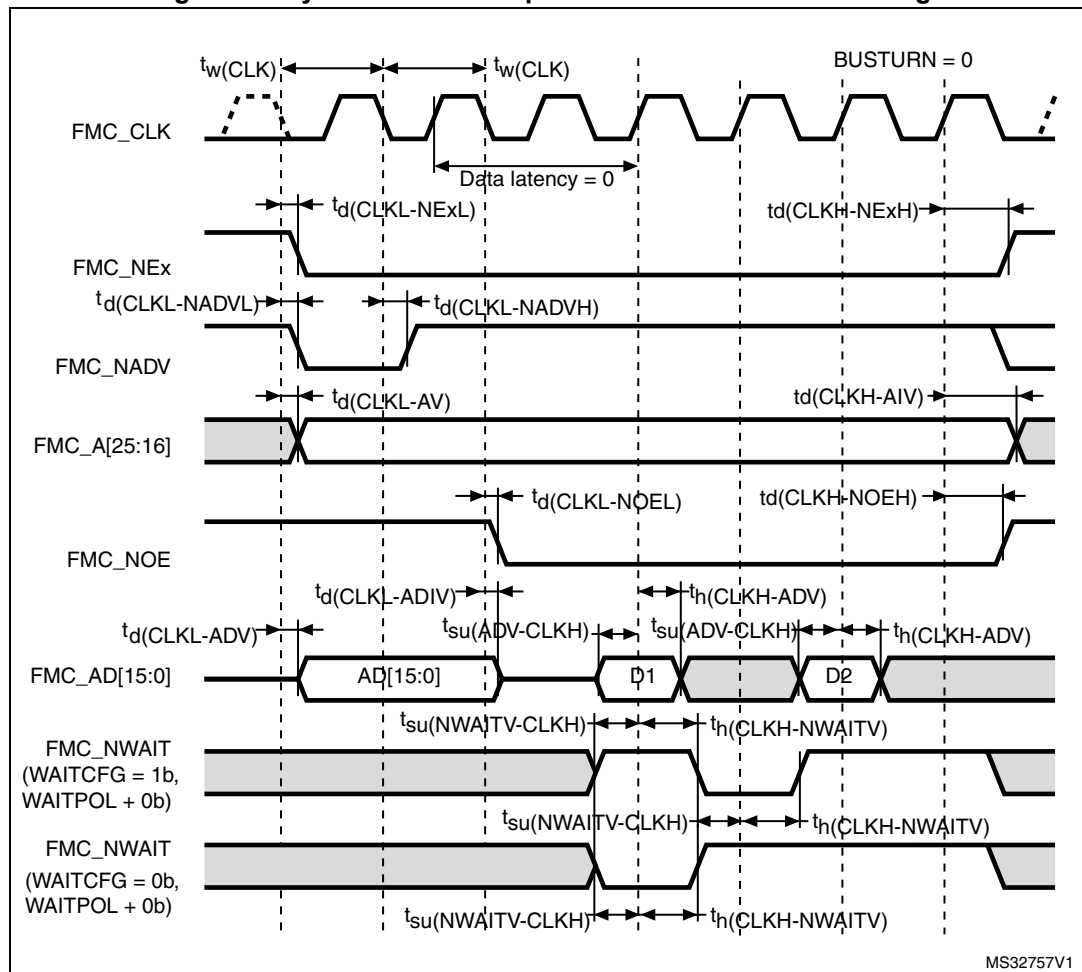
f_{PLL_IN} and f_{Mod} must be expressed in Hz.

As an example:

If f_{PLL_IN} = 1 MHz, and f_{MOD} = 1 kHz, the modulation depth (MODEPER) is given by equation 1:

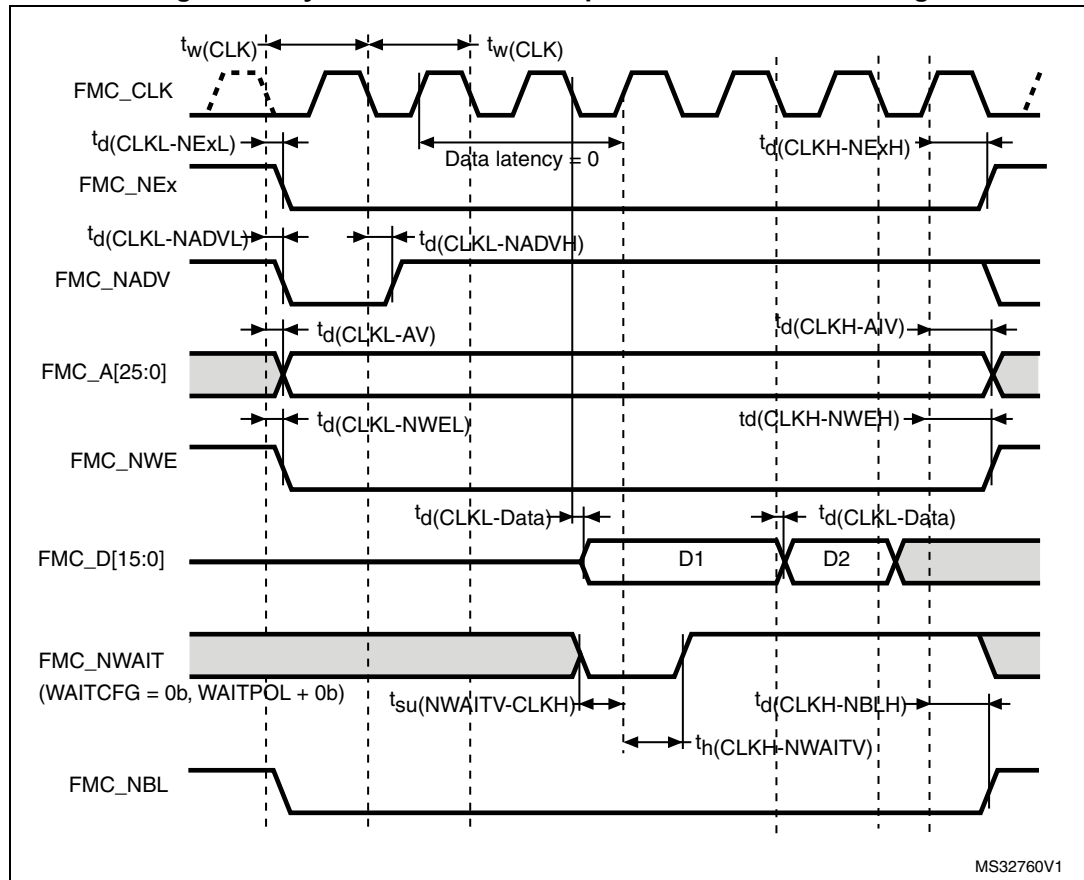
$$\text{MODEPER} = \text{round}[10^6 / (4 \times 10^3)] = 250$$

Figure 62. Synchronous multiplexed NOR/PSRAM read timings



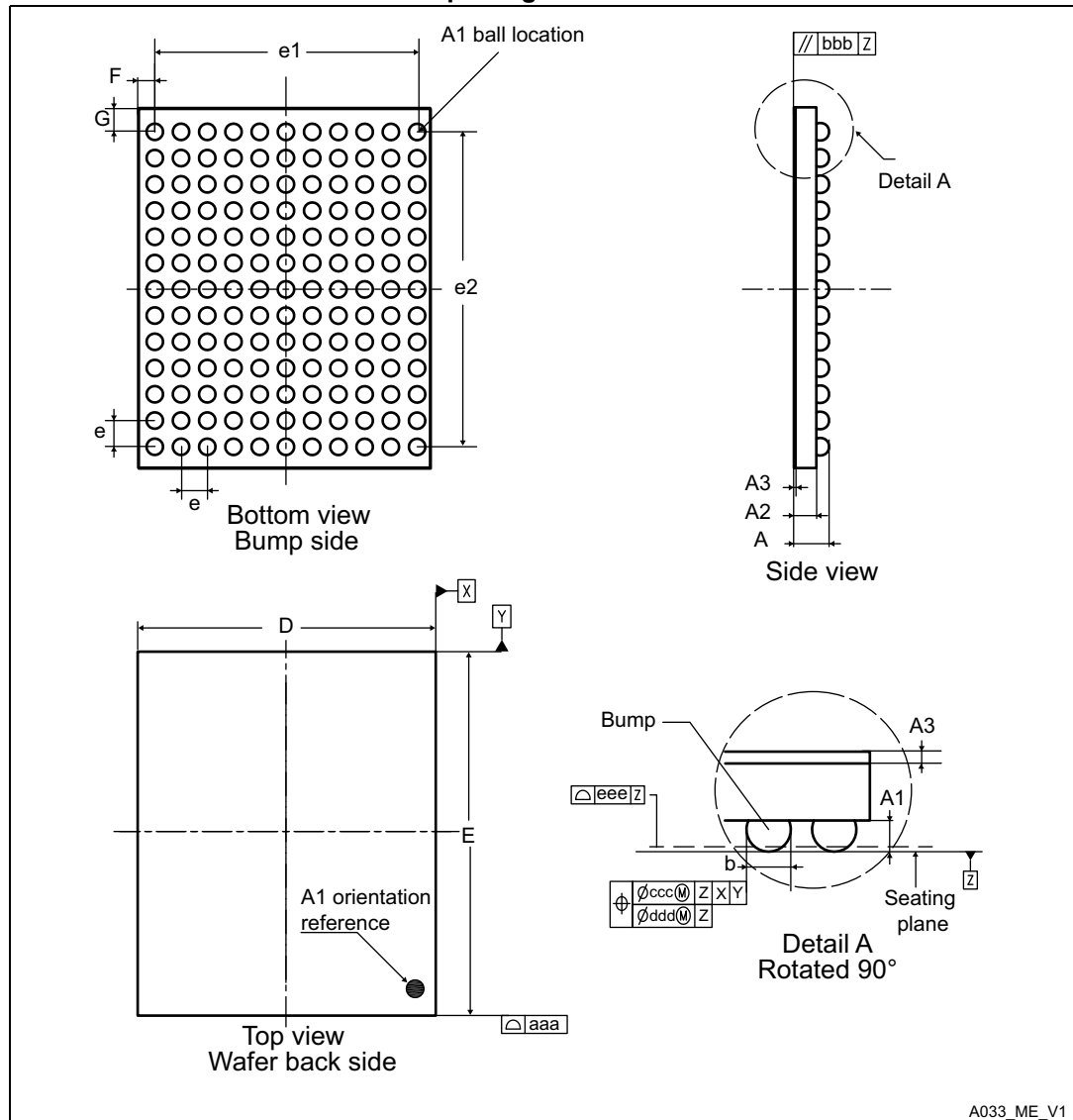
1. Guaranteed by characterization results.

Figure 65. Synchronous non-multiplexed PSRAM write timings



6.3 WLCSP143, 4.539x 5.849 mm, 0.4 mm pitch wafer level chip scale package information

Figure 85. WLCSP143, 4.539x 5.849 mm, 0.4 mm pitch wafer level chip scale package outline



1. Drawing is not to scale.

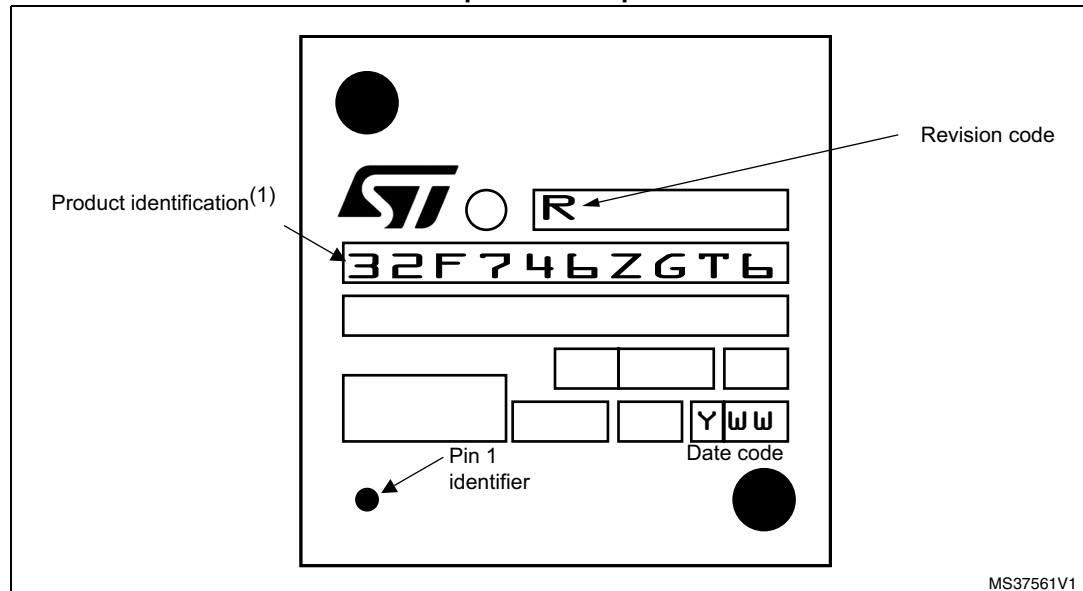
Table 115. WLCSP143, 4.539x 5.849 mm, 0.4 mm pitch wafer level chip scale package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.525	0.555	0.585	0.0207	0.0219	0.0230
A1	-	0.175	-	-	0.0069	-

Marking of engineering samples

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Figure 90. LQFP144, 20 x 20mm, 144-pin low-profile quad flat package top view example



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.